

View Online at <https://aerobasegroup.com/nsn/5961-01-580-4459>

Overall Length:

6.60 millimeters

Terminal Length:

2.75 millimeters

Overall Height:

10.0 millimeters

Overall Width:

2.30 millimeters

Features Provided:

High power

Semiconductor Material:

Silicon

Maximum Operating Temperature Per Measurement Point:

175.0 degrees celsius junction

Product Name:

N-channel trenchmos siliconmax standard level fet

Special Features:

Fet = field-effect transistor (trenchmos technology)

Special Test Features:

High operating power, low conduction losses, suitable for high frequency applications

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0